

PATENT ASSIGNMENT COVER SHEET

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Stylesheet Version v1.2

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
DUK-KYU BAE	01/11/2017
YOUNG-BOO MOON	01/11/2017
YONGJO PARK	01/11/2017
RECEIVING PARTY DATA	
Name:	HEXASOLUTION CO., LTD.
Street Address:	9F., C DONG, 145, GWANGGYO-RO, YEONGTONG-GU, SUWON-SI
City:	GYEONGGI-DO
State/Country:	KOREA, REPUBLIC OF
Postal Code:	443-270
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	15326256
CORRESPONDENCE DATA	
Fax Number:	(312)637-3006
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
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Correspondent Name:	L. FRIEDMAN/HAHN LOESER & PARKS, LLP - CHICAGO
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ATTORNEY DOCKET NUMBER:	213464/1
NAME OF SUBMITTER:	L. FRIEDMAN
SIGNATURE:	/lfriedman/
DATE SIGNED:	01/13/2017
This document serves as an Oath/Declaration (37 CFR 1.63).	
Total Attachments: 3	
source=Decl-Assgnmnts#page1.tif	
source=Decl-Assgnmnts#page2.tif	

INVENTOR DECLARATION/ASSIGNMENT

As a below-named inventor, I hereby declare that:

This declaration is directed to international application no. **PCT/KR2015/006263**, filed on 19 June 2015 and entitled Substrate Structure, Method for Forming Same, and Method for Manufacturing Nitride Semiconductor Using Same.

The above-identified application was made or authorized to be made by me.

I am the original inventor or an original joint inventor of the claimed invention in the above-identified application.

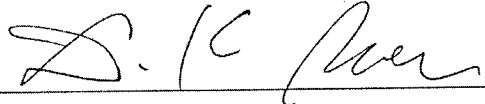
I acknowledge the duty to disclose to the USPTO all information known to me to be material to patentability of the above-identified application as defined in 37 C.F.R. §1.56.

I acknowledge that any willful false statement made in this declaration is punishable under 18 U.S.C. §1001 by fine or imprisonment of not more than five years, or both.

For valuable consideration, adequacy and receipt of which is hereby acknowledged, I have assigned and do hereby assign to **Hexasolution Co., Ltd.**, a company organized under the laws of the Republic of Korea and having an office at 9F., C Dong, 145, Gwanggyo-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do 443-270 Republic of Korea, its successors and assigns, the entire right, title and interest of me in the above-identified application no. PCT/KR2015/006263; and in and to all present and future applications for patents and Letters Patent therefor, including Convention and Treaty rights of all kinds, in all countries throughout the world, for all such subject matter, including all divisions, reissues, continuations in whole or in part, renewals, substitutes, and extensions of said applications for patent and Letters Patent, and all rights of priority resulting from the filing of the above-identified international application.

I agree to sign all documents as may be necessary to secure and enforce all said applications and Letters Patent and rights, including any reissue thereof, and as may be necessary in any contested proceedings in which said applications or patents issued therefrom may become involved, and I request issuance of all said Letters Patent to the above assignee in accordance with this assignment.

Date: 11. Jan. 2017

 (signature)

BAE, Duk-Kyu
4201-1201, 11, Dongbaek 2-ro,
Giheung-gu, Yongin-si, Gyeonggi-do 446-916
Republic of Korea
Nationality: KR

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Date: 2016. 1. 11

 (signature)

MOON, Young-Boo
205-1302, 15, Yonggu-daero 2518beon-gil,
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Nationality: KR

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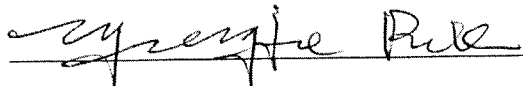
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Date: Jan 11, 2017

 (signature)

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1203-2103, 10, Dongcheon-ro 113beon-gil,
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